

STPS30SM100S

Power Schottky rectifier

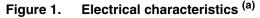
Features

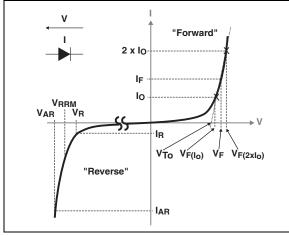
- High current capability
- Avalanche rated
- Low forward voltage drop current
- High frequency operation
- Insulated package:
 - Insulation voltage 2000 V rms
 - Package capacitance = 12 pF

Description

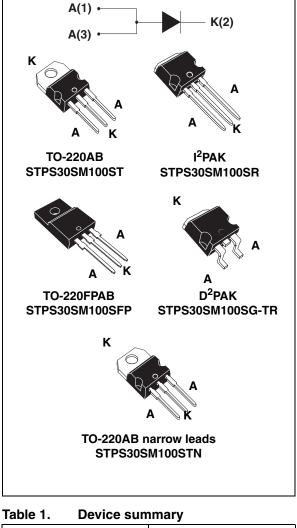
This single Schottky rectifier is suited for high frequency switch mode power supply.

Packaged in TO-220AB, TO-220AB narrow leads, TO-220FPAB, D²PAK and I²PAK, this device is intended to be used in notebook, game station and desktop adaptors, providing in these applications a good efficiency at both low and high load.





 V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 13*. V_{AR} and I_{AR} are pulse measurements (t_p < 1 μs). V_R, I_R, V_{RRM} and V_F, are static characteristics



	-
I _{F(AV)}	30 A
V _{RRM}	100 V
T _j (max)	150 °C
V _F (typ)	0.420 V

September 2011

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1 Characteristics

Table 2.	Absolute ratings (limiting values with terminals 1 and 3 short circuited)
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Symbol	Pa	arameter	Value	Unit
V _{RRM}	Repetitive peak reverse voltage		100	V
I _{F(RMS)}	Forward current rms		60	Α
I _{F(AV)}	Average forward current $\delta = 0.5$	TO-220AB, TO-220AB narrow leads, D ² PAK, I ² PAK, T _c = 125 °C	30	А
. ()		TO-220FPAB, T _c = 80 °C		
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal, terminals 1 and 3 short circuited	530	A
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power	$t_p = 1 \ \mu s T_j = 25 \ ^\circ C$	21500	W
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	t _p < 1 μs T _j < 150 °C I _{AR} < 53.8 A	120	v
V _{ASM} ⁽²⁾	Maximum single pulse peak avalanche voltage	t _p < 1 μs T _j < 150 °C I _{AR} < 53.8 A	120	v
T _{stg}	Storage temperature range		-65 to + 175	°C
Тj	Maximum operating junction tempera	150	°C	

1. For temperature or pulse time duration deratings, refer to *Figure 4*. and *Figure 5*.. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

2. Refer to *Figure 13*.

3. $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

Table 3.Thermal resistance

Symbol		Parameter			
R _{th(i-c)}	Junction to case	TO-220AB, TO-220AB narrow leads, D ² PAK, I ² PAK	1	°C/W	
		TO-220FPAB	4		

Table 4. Static electrical characteristics (terminals 1 and 3 short circuited)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _B ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V – V			45	μA
'R`´	neverse leakage current	T _j = 125 °C	$V_{R} = V_{RRM}$		15	45	mA
		T _j = 25 °C	1 - 5 4		500		
	$V_{F}^{(2)}$ Forward voltage drop $T_{j} = 125 \text{ °C}$ $T_{j} = 25 \text{ °C}$ $T_{j} = 125 \text{ °C}$ $T_{j} = 125 \text{ °C}$ $T_{j} = 25 \text{ °C}$ $T_{j} = 125 \text{ °C}$	$T_i = 25 \text{ °C}$		420			
V (2)				600	670	mV	
VF` '		T _j = 125 °C	F = TOA		505	560	mv
		L = 20 A		780	870		
		T _j = 125 °C	$I_F = 30 \text{ A}$		630	690	

1. Pulse test: $t_p = 5 \text{ ms}, \delta < 2\%$

2. Pulse test: $t_p = 380 \ \mu s, \ \delta < 2\%$

To evaluate the conduction losses use the following equation: P = 0.580 x ${I_{F(AV)}}$ + 0.0033 x ${I_{F}}^2_{(RMS)}$



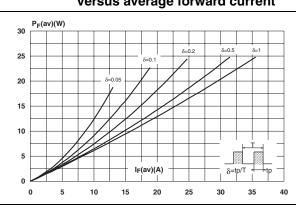


Figure 2. Average forward power dissipation Figure 3. versus average forward current



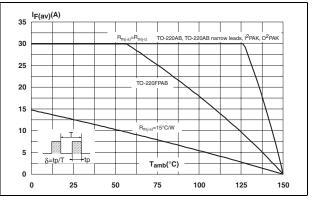


Figure 4. Normalized avalanche power derating versus pulse duration

Figure 5. Normalized avalanche power derating versus junction temperature

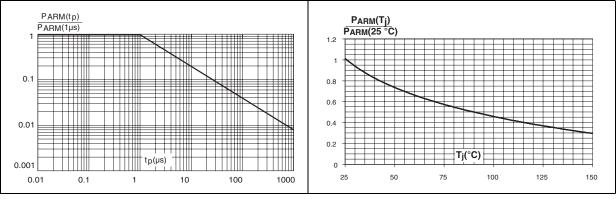
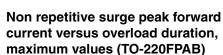


Figure 6. Non repetitive surge peak forward Figure 7. current versus overload duration, maximum values



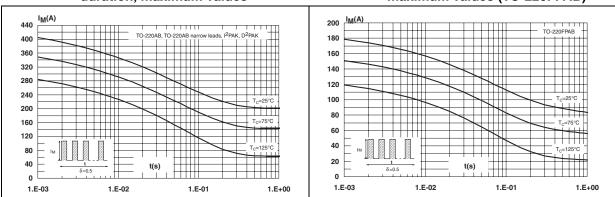
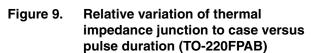




Figure 8. Relative variation of thermal impedance junction to case versus pulse duration



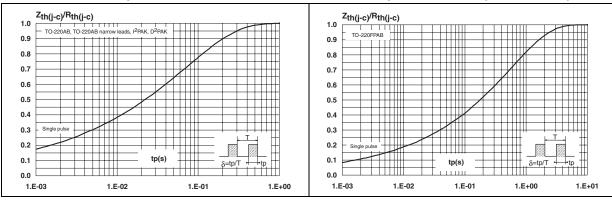


Figure 10. Reverse leakage current versus reverse voltage applied (typical values)

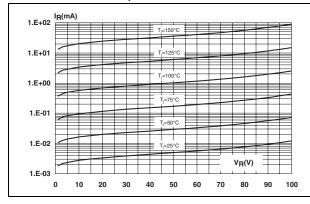
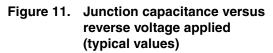


Figure 12. Forward voltage drop versus forward current (terminals 1 and 3 short circuited)



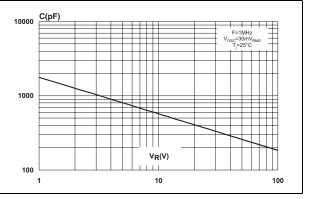
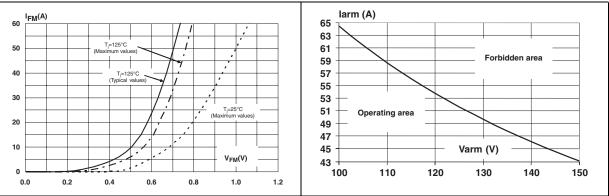


Figure 13. Reverse safe operating area $(t_p < 1 \ \mu s \ and \ T_j < 150 \ ^{\circ}C)$





2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

Table 5. TO-220AB dimensions

			Dimer	nsions	
	Ref.	Millin	neters	Inches	
		Min.	Max.	Min.	Max.
	Α	4.40	4.60	0.173	0.181
	С	1.23	1.32	0.048	0.051
	D	2.40	2.72	0.094	0.107
	E	0.49	0.70	0.019	0.027
	F	0.61	0.88	0.024	0.034
	F1	1.14	1.70	0.044	0.066
	F2	1.14	1.70	0.044	0.066
F2	G	4.95	5.15	0.194	0.202
$ \begin{array}{c c} & F1 & F1 \\ \hline & F1 &$	G1	2.40	2.70	0.094	0.106
	H2	10	10.40	0.393	0.409
F	L2	16.4	typ.	0.645 typ.	
	L4	13	14	0.511	0.551
	L5	2.65	2.95	0.104	0.116
G	L6	15.25	15.75	0.600	0.620
	L7	6.20	6.60	0.244	0.259
	L9	3.50	3.93	0.137	0.154
	М	2.6	typ.	0.102	2 typ.
	Diam.	3.75	3.85	0.147	0.151



					Dimer	sions		
		Ref.	Ref. Millimeter		rs	Inches		s
			Min.	Тур.	Max.	Min.	Тур.	Max.
		А	4.40		4.60	0.17		0.18
۹P	A	b	0.61		0.88	0.024		0.034
E	F	b1	0.95		1.20	0.037		0.047
	A A	с	0.48		0.70	0.019		0.027
	H1	D	15.25		15.75	0.60		0.62
		D1		1.27			0.05	
L20		E	10.00		10.40	0.39		0.41
		е	2.40		2.70	0.094		0.106
b1(x3)		e1	4.95		5.15	0.19		0.20
	- - -J1- 4	F	1.23		1.32	0.048		0.052
		H1	6.20		6.60	0.24		0.26
	-= C	J1	2.40		2.72	0.095		0.107
		L	13.00		14.00	0.51		0.55
-e1		L1	2.60		2.90	0.102		0.114
		L20		15.40			0.61	
		L30		28.90			1.14	
		ØP	3.75		3.85	0.147		0.151
		Q	2.65		2.95	0.104		0.116

 Table 6.
 TO-220AB narrow leads dimensions



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			Dimer	nsions	
	Ref.	Millin	neters	Inches	
		Min.	Max.	Min.	Max.
	Α	4.4	4.6	0.173	0.181
	В	2.5	2.7	0.098	0.106
	D	2.5	2.75	0.098	0.108
	E	0.45	0.70	0.018	0.027
Dia	F	0.75	1	0.030	0.039
	F1	1.15	1.70	0.045	0.067
L2 L7	F2	1.15	1.70	0.045	0.067
	G	4.95	5.20	0.195	0.205
	G1	2.4	2.7	0.094	0.106
	Н	10	10.4	0.393	0.409
L4	L2	16	Тур.	0.63 Тур.	
	L3	28.6	30.6	1.126	1.205
G1 ↔	L4	9.8	10.6	0.386	0.417
G G	L5	2.9	3.6	0.114	0.142
	L6	15.9	16.4	0.626	0.646
	L7	9.00	9.30	0.354	0.366
	Dia.	3.00	3.20	0.118	0.126

Table 7. TO-220FPAB dimensions



Devices in I²PAK with nickel-plated back frame must NOT be mounted by frame soldering like SMDs. Such devices are intended to be through-hole mounted ONLY and in no circumstances shall ST be held liable for any lack of performance or damage arising out of soldering of nickel-plated back frames.

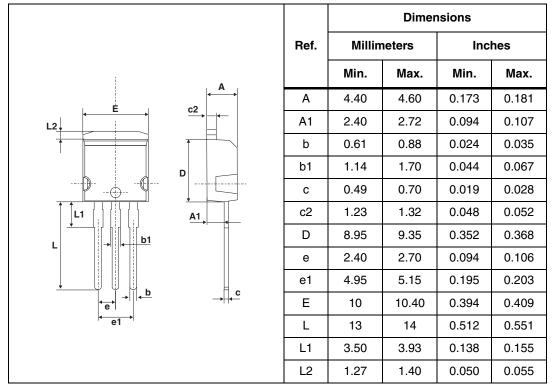


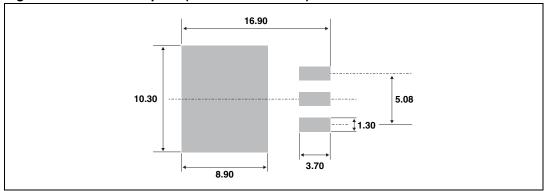
Table 8.I²PAK dimensions



				Dimer	nsions	
		Ref.	Millim	neters	Inc	hes
			Min.	Max.	Min.	Max.
		Α	4.40	4.60	0.173	0.181
		A1	2.49	2.69	0.098	0.106
	C2→→←	A2	0.03	0.23	0.001	0.009
	1 I	В	0.70	0.93	0.027	0.037
L	D	B2	1.14	1.70	0.045	0.067
		С	0.45	0.60	0.017	0.024
		C2	1.23	1.36	0.048	0.054
		D	8.95	9.35	0.352	0.368
G		Е	10.00	10.40	0.393	0.409
	A2	G	4.88	5.28	0.192	0.208
		L	15.00	15.85	0.590	0.624
	M +	L2	1.27	1.40	0.050	0.055
	* FLAT ZONE NO LESS THAN 2mm	L3	1.40	1.75	0.055	0.069
	FLAT ZONE NO LESS THAN 2MM	М	2.40	3.20	0.094	0.126
		R	0.40	typ.	0.016	6 typ.
		V2	0°	8°	0°	8°

Table 9.D²PAK dimensions

Figure 14. D²PAK footprint (dimensions in mm)





3 Ordering information

Table 10.Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS30SM100ST	PS30SM100ST	TO-220AB	2.2 g	50	Tube
STPS30SM100SFP	PS30SM100SFP	TO-220FPAB	1.70 g	50	Tube
STPS30SM100SR	PS30SM100SR	I ² PAK	1.49 g	50	Tube
STPS30SM100SG-TR	PS30SM100SG	D ² PAK	1.48 g	1000	Tape and reel
STPS30SM100STN	PS30SM100STN	TO-220AB narrow leads	1.9 g	50	Tube

4 Revision history

Table 11. Document revision history

Date	Revision	Changes
25-Mar-2009	1	First issue
16-Apr-2010	2	Updated package graphic for TO-220AB on front page and in <i>Table 5</i> .
28-Jan-2011	3	Added warning paragraph above <i>Table 8</i> .
15-Sep-2011	4	Added TO-220AB narrow leads package.



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